L Number	Hits	Search Text	DB	Time stamp
15	2	6058125.URPN.	USPAT	2004/03/04 16:16
16	1	"5278926".PN.	USPAT	2004/03/04 16:17
20	7	6037189.URPN.	USPAT	2004/03/04 16:17
21	11645	(372/43,45,46,50).CCLS.	USPAT;	2004/03/04 16:24
		(US-PGPUB;	
ĺ			ЕРО; ЛРО;	
i			DERWENT	
22	4239	((372/43,45,46,50).CCLS.) and (stripe ridge) and semiconductor	USPAT;	2004/03/04 16:24
22	4239	((372/43,43,40,30).CCLS.) and (surperrage) and semiconductor		2004/03/04 10:24
			US-PGPUB;	
			ЕРО; ЈРО;	
			DERWENT	
23	3758	(((372/43,45,46,50).CCLS.) and (stripe ridge) and semiconductor) and	USPAT;	2004/03/04 16:25
		substrate	US-PGPUB;	
			ЕРО; ЈРО;	
			DERWENT	
24	260	(((((372/43,45,46,50).CCLS.) and (stripe ridge) and semiconductor) and	USPAT;	2004/03/04 16:26
		substrate) and (edge near3 emitt\$5)	US-PGPUB,	
			ЕРО; ЛРО;	
			DERWENT	
25	1911	(((((372/43,45,46,50).CCLS.) and (stripe ridge) and semiconductor) and	USPAT;	2004/03/04 16:26
23	1911	substrate) and (stripe ridge) with active	US-PGPUB;	2004/03/04 10:20
		substrate) and (surperridge) with active	EPO; JPO;	
			DERWENT	0004/00/04 16 06
26	130	((((((372/43,45,46,50).CCLS.) and (stripe ridge) and semiconductor) and	USPAT;	2004/03/04 16:26
		substrate) and (edge near3 emitt\$5)) and (((((372/43,45,46,50).CCLS.)	US-PGPUB;	
		and (stripe ridge) and semiconductor) and substrate) and (stripe ridge)	ЕРО; ЈРО;	
		with active)	DERWENT	
-	4405	(semiconductor near3 laser) same (stripe ridge mesa)	USPAT;	2003/08/14 13:02
			ЕРО; ЛРО;	
			IBM_TDB	
-	2371	((semiconductor near3 laser) same (stripe ridge mesa)) and 372/\$.ccls.	USPĀT;	2003/08/20 15:14
		((commonweal)	ЕРО; ЈРО;	
			IBM TDB	
	112	(((semiconductor near3 laser) same (stripe ridge mesa)) and 372/\$.ccls.)	USPAT;	2003/08/12 18:44
-	112	and edge near2 emit\$4	EPO; JPO;	2005/00/12 10.11
		and edge nearz ennus4		
	_	COO 400 C VID DVI	IBM_TDB	2002/09/12 19:20
-	7		USPAT	2003/08/12 18:20
-	18		USPAT	2003/08/12 18:22
		"4901324" "4941726" "5119460" "5166940" "5265177"		
		"5422897" "5455879" "5530710" "5659644" "5710789"		
		"5774484" "5864644" "5940557").PN.		
-	4	6134368.URPN.	USPAT	2003/08/12 18:31
-	4	("5284791" "5360763" "5382543" "5717710").PN.	USPAT	2003/08/12 18:33
-	2	nichia.as. and (edge with emit\$4) and laser	USPAT;	2003/08/12 18:46
	_		ЕРО; ЛРО;	
			IBM_TDB	
_	212	nichia.as. and laser	USPAT;	2003/08/12 18:46
-	212	ilicilia.as. and laser	EPO; JPO;	2005/00/12 10:10
	5 0		IBM_TDB	2002/09/12 19:5/
-	70	(nichia.as. and laser) and (ridge stripe)	USPAT;	2003/08/12 18:50
			ЕРО; ЈРО;	
			IBM_TDB	
-	11910	372/43-50.ccls.	USPAT;	2003/08/12 19:18
			ЕРО; ЈРО;	
			IBM_TDB	
	665	372/43-50.ccls. and (edge with emit\$5)	USPĀT;	2003/08/12 18:50
	1		EPO; JPO;	
	i		IBM TDB	
	301	(272/12 50 cole and (adae with amit\$5)) and (ridge string)	USPAT;	2003/08/12 18:50
-	281	(372/43-50.ccls. and (edge with emit\$5)) and (ridge stripe)		2003/00/12 18.30
			ЕРО; ЛРО;	
	I		IBM_TDB	}

	·			
-	192	((372/43-50.ccls. and (edge with emit\$5)) and (ridge stripe)) not	USPAT;	2003/08/12 18:51
Ì		(((((semiconductor near3 laser) same (stripe ridge mesa)) and	ЕРО; ЈРО;	
		372/\$.ccls.) and edge near2 emit\$4)	IBM_TDB	
-	80	(((372/43-50.ccls. and (edge with emit\$5)) and (ridge stripe)) not	USPAT;	2003/08/12 18:52
		((((semiconductor near3 laser) same (stripe ridge mesa)) and	ЕРО; ЛРО;	
}	1	372/\$.ccls.) and edge near2 emit\$4)) and (film "Si0.sub.2" "TiO" "SiO")	IBM_TDB	
-	1	(((372/43-50.ccls. and (edge with emit\$5)) and (ridge stripe)) not	USPAT;	2003/08/12 18:52
]	((((semiconductor near3 laser) same (stripe ridge mesa)) and	ЕРО, ЈРО,	
	1	372/\$.ccls.) and edge near2 emit\$4)) and (shad\$4 with film)	IBM_TDB	
-	5	6034983.URPN.	USPAT	2003/08/12 19:01
-	13	("5011550" "5079184" "5130269" "5227328" "5229319"	USPAT	2003/08/12 19:03
		"5266127" "5300186" "5399522" "5424243" "5574289"		
		"5657338" "5787106" "5790578").PN.		
_	219	372/43-50.ccls. and (edge with emitting) and (stripe ridge) and active	USPAT;	2003/08/12 19:40
		and semiconductor and substrate	EPO; JPO;	2005/00/12 15:10
		and semiconductor and substate	IBM_TDB	
	2	372/43-50.ccls. and (edge with emitting) and (stripe ridge) and (shad\$3	USPAT;	2003/08/12 19:48
-		with film)		2003/06/12 19.46
		widi iiiii)	ЕРО; ЈРО;	
	4101	(272/42 50) 001 9	IBM_TDB	2002/00/14 12 02
-	4191	(372/43-50).CCLS.	USPAT	2003/08/14 13:03
-	2807	(372/49,9,50,108,101).CCLS.	USPAT	2003/08/14 13:03
-	1172	((372/49,9,50,108,101).CCLS.) and lens	USPAT	2003/08/14 13:04
-	881	((372/43-50).CCLS.) and lens	USPAT	2003/08/14 14:13
-	7	5966399.URPN.	USPAT	2003/08/14 13:50
-	2	("5426657" "5838715").PN.	USPAT	2003/08/14 13:51
-	7	5553089.URPN.	USPAT	2003/08/14 14:03
-	3	("5081639" "5086431" "5212706").PN.	USPAT	2003/08/14 14:03
-	655	(((372/49,9,50,108,101).CCLS.) and lens) not (((372/43-50).CCLS.) and	USPAT	2003/08/14 14:25
		lens)		
-	2483	372/43-50.ccls. and (ridge stripe mesa)	USPAT	2003/08/14 14:25
-	486	(372/43-50.ccls. and (ridge stripe mesa)) and lens	USPAT	2003/08/14 14:26
-	0	((372/43-50.ccls. and (ridge stripe mesa)) and lens) not	USPAT	2003/08/14 14:30
		(((((372/43-50).CCLS.) and lens) (((372/49,9,50,108,101).CCLS.) and		
		lens))		
-	1	6167070.pn.	USPAT	2003/08/14 14:31
-	1	6037189.pn.	USPAT	2003/08/14 15:02
-	1205	(372/43-50.ccls. and (ridge stripe mesa)) and (film passivation)	USPAT	2003/08/14 15:04
-	1165	372/46.ccls. and (stripe ridge)	USPAT	2003/08/14 15:04
-	666	(372/46.ccls. and (stripe ridge)) and (film passivation)	USPAT	2003/08/14 15:06
-	50	(372/46.ccls. and (stripe ridge)) and (passivation)	USPAT	2003/08/14 15:26
-	9	(372/46.ccls. and (stripe ridge)) and (SiO TiO) near3 (layer film)	USPAT	2003/08/14 15:26
-	26	(US-6463087-\$ or US-6134368-\$ or US-6374028-\$ or US-6455342-\$ or	USPAT	2003/08/14 15:52
		US-6327288-\$ or US-6034983-\$ or US-6219366-\$ or US-6465269-\$ or	001111	2005/00/14 15.52
		US-5790578-\$ or US-5665985-\$ or US-6586776-\$ or US-6167070-\$ or		
		US-6122417-\$ or US-6058125-\$ or US-6037189-\$ or US-5970081-\$ or		
		US-5966399-\$ or US-5835517-\$ or US-5553089-\$ or US-5428227-\$ or		
1		US-5457569-\$ or US-6472691-\$ or US-5659565-\$ or US-5640410-\$ or		
		US-5333141-\$ or US-4813054-\$).did.		
<u>-</u>	1481		IICDAT	2002/09/20 15 15
-	233	((semiconductor near3 laser) same (stripe ridge mesa)) and 372/\$.ccls. (((semiconductor near3 laser) same (stripe ridge mesa)) and 372/\$.ccls.)	USPAT	2003/08/20 15:15
_	233	(((semiconductor near3 laser) same (stripe ridge mesa)) and 3/2/\$.ccis.) and nitride	USPAT	2003/08/20 15:19
	100		LIODAT	2002/00/20 17.50
-	198	((((semiconductor near3 laser) same (stripe ridge mesa)) and	USPAT	2003/08/20 15:20
L		372/\$.ccls.) and nitride) and (film dielectric passivation SiO TiO)		1